A product Line of
Diodes Incorporated

PI90LV01/PI90LVB01

SOTiny LVDS High-Speed Differential Line Driver

Features

- ➔Meets or Exceeds ANSI TIA/EIA-644-1955 Standard
- ➔Signaling rates up to 660 Mbps
- ➔Bus-Terminal ESD exceeds 2kV
- ➔Low-Voltage Differential Signaling with typical Output Voltages of 350mV:
  - 100-ohm load (PI90LV01)
  - 50-ohm load (PI90LVB01)
- ➔Typical Propagation Delay Times of 1.5ns
- ➔Typical Power Dissipation of 20mW @200 MHz
- ➔Low-Voltage TTL (LVTTL) Level is 5V Tolerant
- ➔Operates from a 3.3V supply
- ➔Extended Industrial Temperature Operating Range: –40°C to 105°C
- ➔Packaging (Pb-free & Green available):
  - 5-pin space-saving SOT23 (T)

Description

The PI90LV01 and PI90LVB01 are differential line drivers that use low-voltage differential signaling (LVDS) to support data rates up to 660 Mbps. These products are designed for applications requiring high-speed, low-power consumption, low-noise generation, and a small package.

The TIA/EIA-644 standard compliant electrical interface provides a minimum differential output voltage magnitude of 247mV into a 100- ohm load and receipt of 100mV signals with up to 1V of ground potential difference between a transmitter and receiver. The PI90LVB01 doubles the output drive current to achieve LVDS levels with a 50-ohm load.

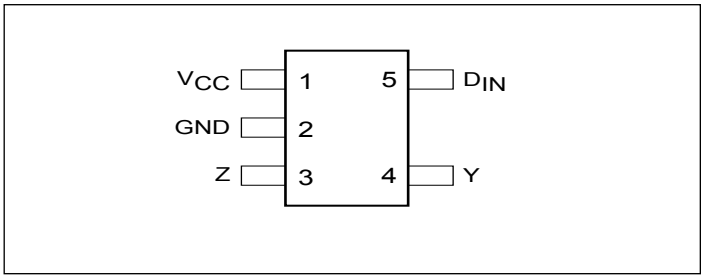
A low-voltage TTL/CMOS input level is translated by the device into a low-voltage (350mV) differential output signal.

Applications

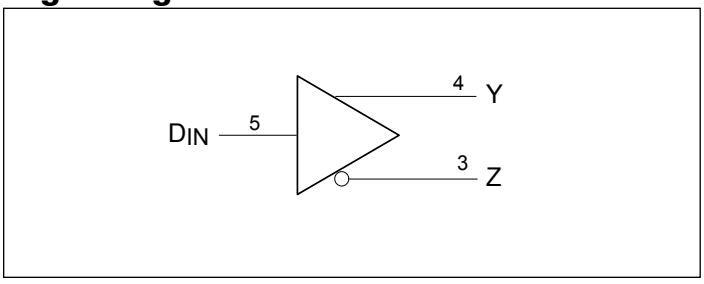
Applications include point-to-point (single termination) and multi-point (double termination) baseband data transmissions over controlled impedance media . The transmission media can be printed circuit board traces, backplanes, or cables.

The PI90LV01 and companion line receivers (PI90LV02 and PI90LVT02) provide new alternatives to RS-232, PECL and ECL devices for high-speed, point-to-point interface applications.

Pinout



Logic Diagram



Function Table

Inputs	Outputs	
D_{IN}	**Y**	**Z**
H	H	L
L	L	H
Open	L	H

Notes:

H = High
L = Low
X = High or Low
High Z = High Impedance

Absolute Maximum Ratings

(Over Operating Free-Air Temperature, unless otherwise noted)†

Supply Voltage Range, VCC(1)	–0.5V to 4V
Input Voltage Range (DIN)	–0.5 to 6V
(Y or Z)	–0.5 to 4V
ESD Rating (HBM, 1.5K-Ohms, 100pF)	≥ 2KV
Continuous total power dissipation	See dissipation rating table
Storage Temperature Range	–65°C to 150°C
Lead Temperature 1.6 mm (1/16 inch) from case for 10 seconds	250°C

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

1. All voltage values, except differential I/O bus voltages, are with respect to ground terminal.

Dissipation Rating Table

Package	$T_A \leq 25°C$ Power Rating	Derating Factor Above $T_A = 25°C$*	$T_A = 85°C$ Power Rating
T	385mW	3.1mW/°C	200mW

*This is the inverse of the junction-to-ambient thermal resistance when board-mounted (low-K) and with no air flow.

Recommended Operating Conditions

	Min.	Nom.	Max.	Units
Supply Voltage, V_{CC}	3.0	3.3	3.6	V
High-Level Input Voltage, V_{IH}	2		3.8	
Low-Level Input Voltage, V_{IL}			0.8	
Operating free-air temperature, T_A	–40		105	°C

Electrical Characteristics (Over Operating Free-Air Temperature, unless otherwise noted)

Symbol	Parameter	Test Conditions		Min.	Typ.(1)	Max.	Units
$\|V_{OD}\|$	Differential output voltage magnitude	R_L = 100 ohms ('LV01) R_L = 50 ohms ('LVB01) See Figure 1		247	350	454	mV
$\Delta\|V_{OD}\|$	Change in differential output voltage magnitude between logic states			–50		50	
$V_{OC(SS)}$	Steady-state common-mode output voltage	See Figure 2		1.125		1.375	V
$\Delta V_{OC(SS)}$	Change in steady-state common-mode output voltage between logic states			–50		50	mV
$V_{OC(PP)}$	Peak-to-peak common-mode output voltage				25	100	
I_{CC}	Supply current	V_I = 0V or V_{CC}, No Load			2	5.5	mA
		V_I = 0V or V_{CC}, R_L = 100 ohms ('LV01)			5.5	8	
		V_I = 0V or V_{CC}, R_L = 50 ohms ('LVB01)			7.0	14	
I_{IH}	High-level input current	V_{IH} = 5V			2	20	µA
I_{IL}	Low-level input current	V_{IL} = 0.8V			2	10	
I_{OS}	Short-circuit output current	V_{ODOUT+} or V_{ODOUT-} = 0V	LV		3	10	mA
			LVB		6	20	
		V_{OD} = 0V	LV			10	
			LVB			20	
$I_{O(OFF)}$	Power-off output current	V_{CC} = 0V, V_O = 3.6V				±1	µA
C_{IN}	Input capacitance				3		pF

Note:
1. All typical values are at 25°C and with a 3.3V

Switching Characteristics, V_{CC} = 3V to 3.6V (Over Operating Free-Air Temperature, unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ.(1)	Max.	Units
t_{PLH}	Propagation delay time, low-to-high level output	PI90LV01, R_L = 100-ohms, C_L = 10pF PI90LVB01, R_L = 50-ohms, C_L = 10pF See Figure 3		1.5	2.7	ns
t_{PHL}	Propogation delay time, high-to-low level output			1.8	2.7	
t_r	Transition, low-to-high (PI90LV01)			0.6	1.5	
	Transition, low-to-high (PI90LBV01)			0.5	1.4	
t_f	Transition, high-to-low (PI90LV01)			0.7	1.5	
	Transition, high-to-low (PI90LBV01)			0.6	1.4	
$t_{sk(p)}$	Pulse skew ($\|t_{PHL} - t_{PLH}\|$)(2)			0.3	-	

Notes:
1. All typical values are at 25°C and with a 3.3V supply
2. $t_{sk(p)}$ is the magnitude of the time difference between the high-to-low and low-to-high propagation delay times at an output
3. f_{max} generator input conditions: 50% duty cycle, 0V to 3V. Output criteria: 45% to 55% duty cycle, V_{OD} = 250mV

Parameter Measurement Information

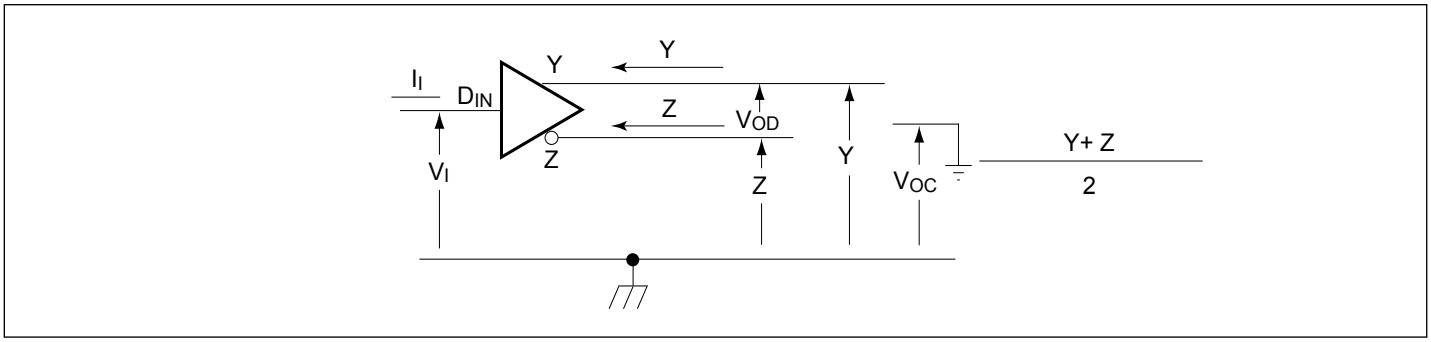


Figure 1. Driver Voltage and Current Definitions

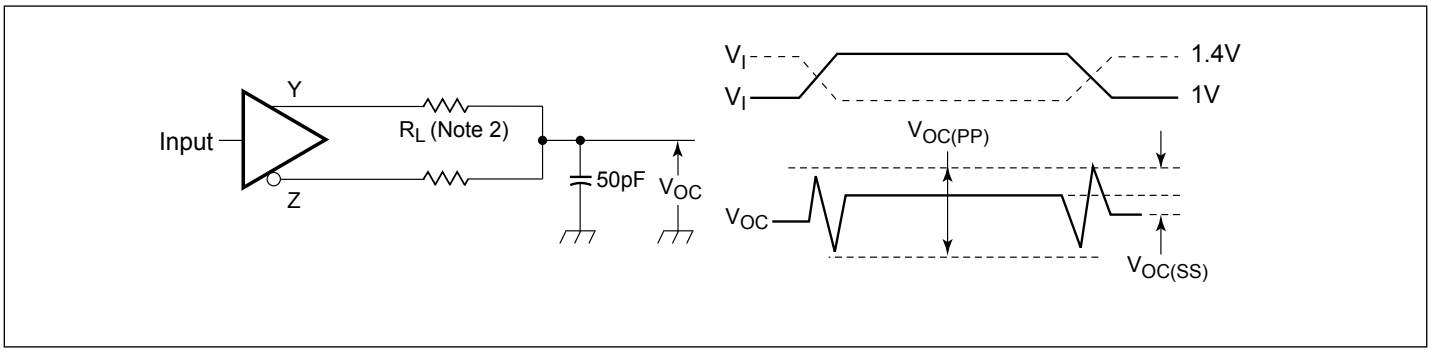
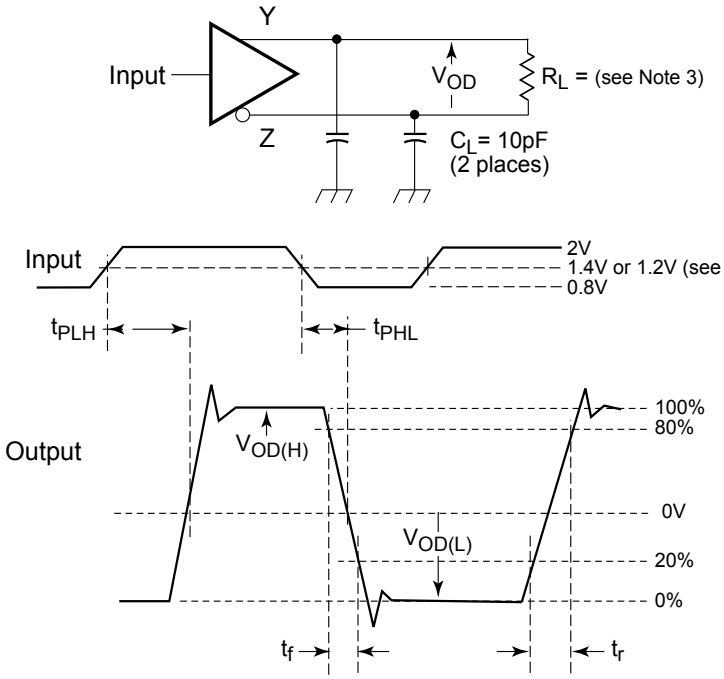


Figure 2. Test Circuit and Definitions for the Driver Common-Mode Output Voltage

Note:

1. All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq$ 1ns, Pulse Repetition Rate (PRR) = 0.5 Mpps, Pulse width = 500 ±10ns. C_L includes instrumentation and fixture capacitance within 0.06mm of the D.U.T. The measurement of $V_{OC(PP)}$ is made on test equipment with a –3dB bandwidth of at least 300MHz.
2. R_L = 49.9 ohms ±1% for PI90LV01 or 24.9 ohms ±1% for PI90LVB01.

Parameter Measurement Information



Note:
1. All input pulses are supplied by a generator having the following characteristics: tr or tf ≤ 1ns, Pulse Repetition Rate (PRR) = 50 Mpps, Pulse width = 10 ±0.2ns. CL includes instrumentation and fixture capacitance within 0.06m of the D.U.T.
2. This point is 1.4V with VCC = 3.3V
3. RL = 100 ohms for PI90LV01 or 50 ohms ±1% for PI90LVB01.

Figure 3. Test Circuit, Timing, & Voltage Definitions for the Differential Output Signal

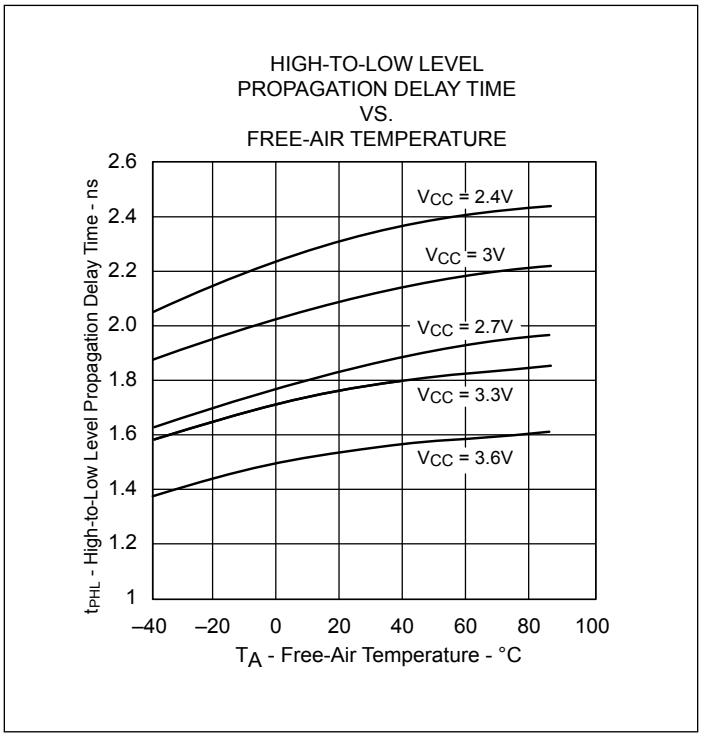


Figure 4.

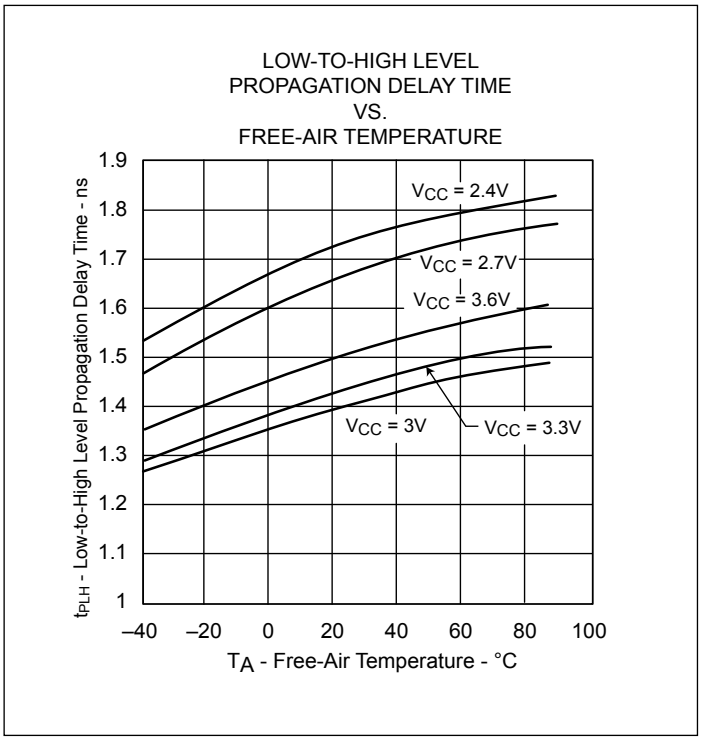
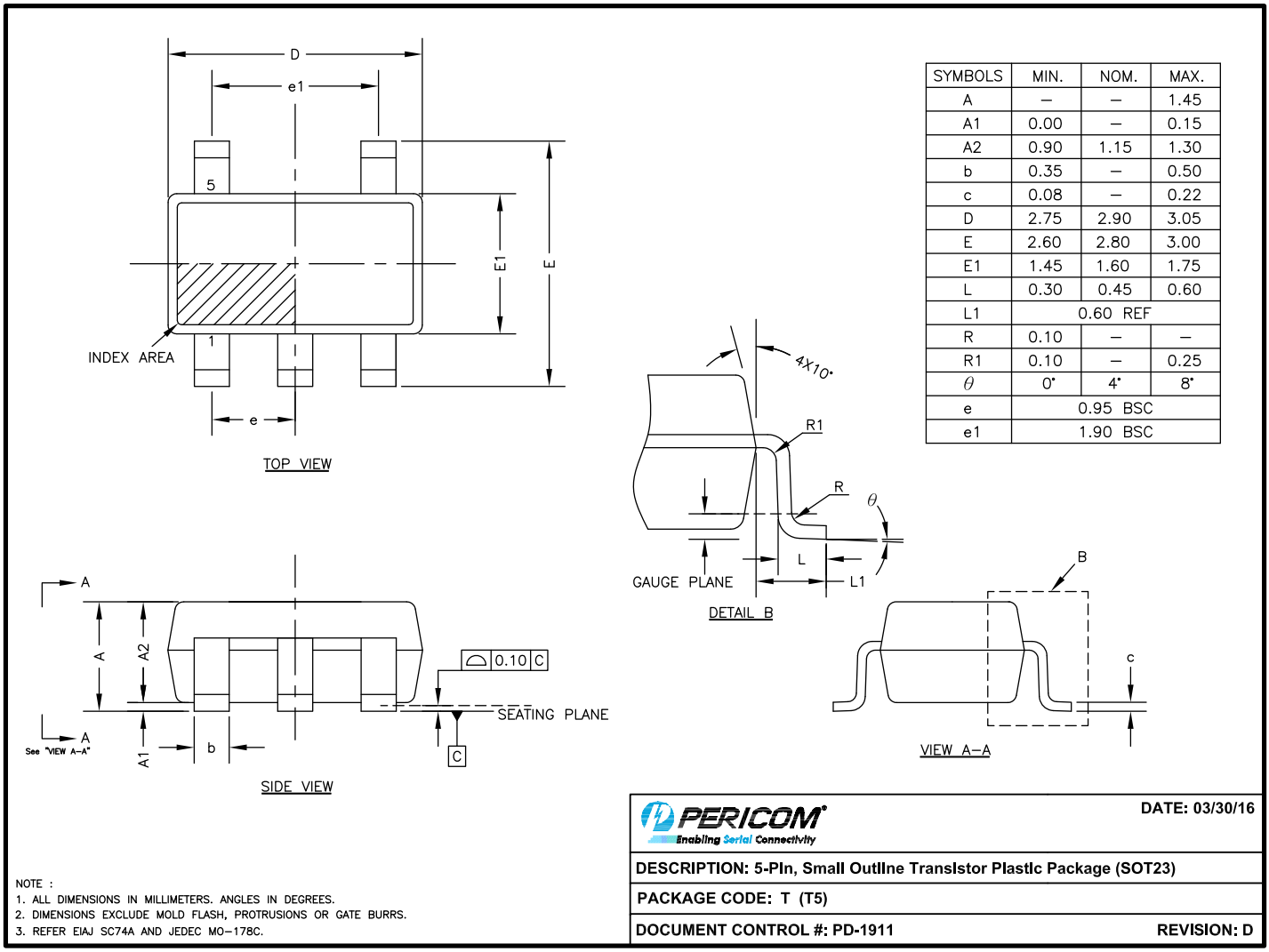


Figure 5.

Packaging Mechanical: 5-Pin SOT23 (T)



SYMBOLS	MIN.	NOM.	MAX.
A	–	–	1.45
A1	0.00	–	0.15
A2	0.90	1.15	1.30
b	0.35	–	0.50
c	0.08	–	0.22
D	2.75	2.90	3.05
E	2.60	2.80	3.00
E1	1.45	1.60	1.75
L	0.30	0.45	0.60
L1	0.60 REF		
R	0.10	–	–
R1	0.10	–	0.25
θ	0°	4°	8°
e	0.95 BSC		
e1	1.90 BSC		

NOTE :
1. ALL DIMENSIONS IN MILLIMETERS. ANGLES IN DEGREES.
2. DIMENSIONS EXCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
3. REFER EIAJ SC74A AND JEDEC MO–178C.

PERICOM Enabling Serial Connectivity — DATE: 03/30/16

DESCRIPTION: 5-Pin, Small Outline Transistor Plastic Package (SOT23)

PACKAGE CODE: T (T5)

DOCUMENT CONTROL #: PD-1911 — REVISION: D

16-0063

For latest package info.
please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Number	Package Code	Package Description	Top Marking
PI90LV01TEX	T	5-Pin, Small Outline Transistor Plastic Package (SOT23)	$\overline{L}$1
PI90LVB01TEX	T	5-Pin, Small Outline Transistor Plastic Package (SOT23)	$\overline{L}$2

Notes:

- Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/
- E = Pb-free and Green
- X suffix = Tape/Reel

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